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Octal D-type Flip-Flops (with 3-state outputs)/ Octal D-type Flip-Flops (with inverted 3-state outputs)

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ADE-205-556 (Z) 1st. Edition Sep. 2000

Description

These device are positive edge triggered flip-flops. The difference between HD74HCT374 and HD74HCT534 is only that the former is a true outputs and the latter is a false outputs. Data at the D inputs, meeting the setup and hold time requirements, are transferred to the Q outputs on positive going transitions of the clock (CK) input. When a high logic level is applied to the output control (OC) input, all outputs go to a high impedance state, regardless of what signals are present at the other inputs and the state of the storage elements.

Features

- LSTTL Output Logic Level Compatibility as well as CMOS Output Compatibility
- High Speed Operation: t_{pd} (Clock to Q) = 15 ns typ ($C_L = 50 \text{ pF}$)
- High Output Current: Fanout of 15 LSTTL Loads
- Wide Operating Voltage: $V_{CC} = 4.5$ to 5.5 V
- Low Input Current: 1 µA max
- Low Quiescent Supply Current: I_{CC} (static) = 4 μ A max (Ta = 25°C)

Function Table

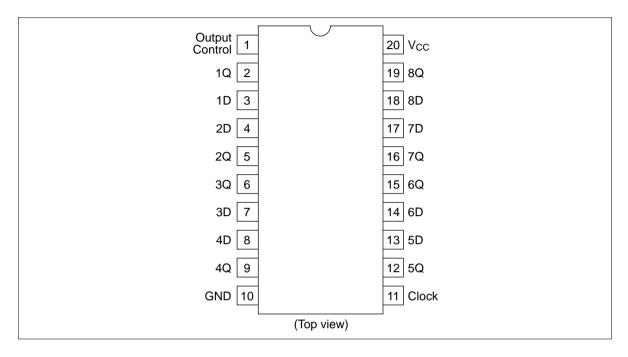
Output Control	Clock	D	HD74HCT374 Q	HD74HCT534 Q
L		Н	Н	L
L		L	L	Н
L	L	Х	No change	No change
Н	Х	Х	Z	Z

X : Irrelevant

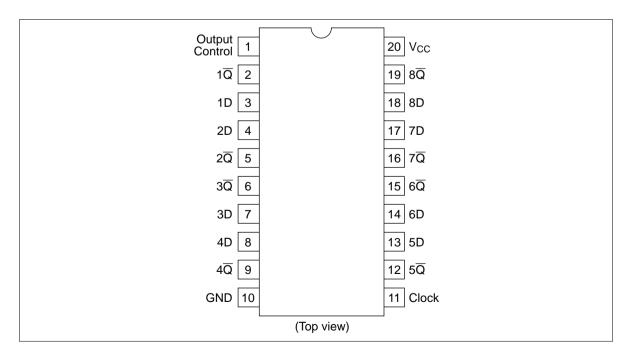
Z : Off (high-impedance) state of a 3-state output.

Pin Arrangement

HD74HCT374



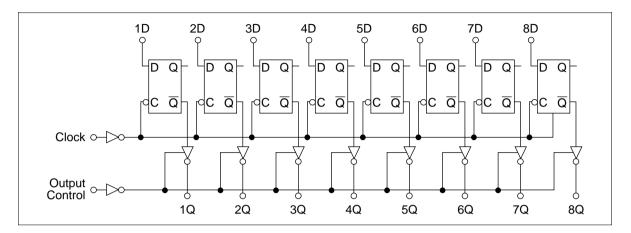
HD74HCT534



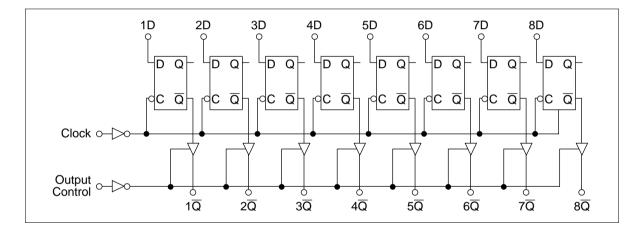
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Block Diagram

HD74HCT374



HD74HCT534



Absolute Maximum Ratings

Item	Symbol	Rating	Unit
Supply voltage range	V _{cc}	-0.5 to +7.0	V
Input voltage	V _{IN}	–0.5 to V _{cc} + 0.5	V
Output voltage	V _{OUT}	-0.5 to V_{cc} + 0.5	V
DC current drain per pin	I _{OUT}	±35	mA
DC current drain per V_{cc} , GND	I _{CC} , I _{GND}	±75	mA
DC input diode current	I _{IK}	±20	mA
DC output diode current	Ι _{οκ}	±20	mA
Power dissipation per package	P _T	500	mW
Storage temperature	Tstg	-65 to +150	°C

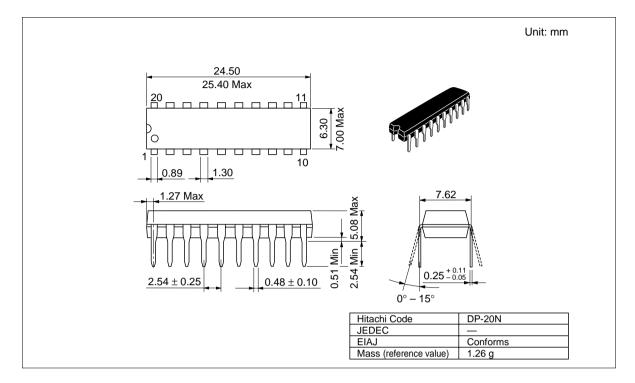
DC Characteristics

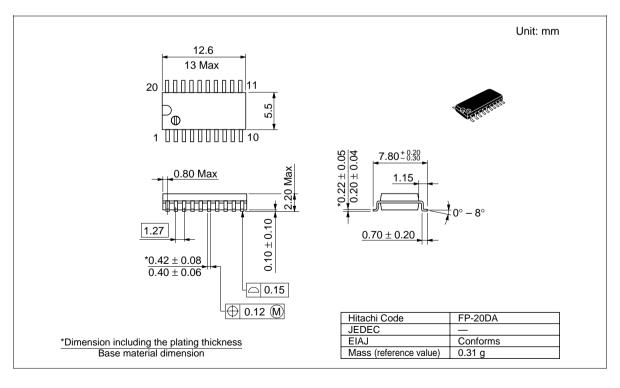
		Ta =	25°C	;	Ta = - +85°0	-40 to C	_	Test Co	onditions
ltem	Symbol	Min	Тур	Max	Min	Мах	Unit	V _{cc} (V)	-
Input voltage	V _{IH}	2.0	—	—	2.0	—	V	4.5 to 5.5	
	V _{IL}	—	—	0.8	—	0.8	V	4.5 to 5.5	
Output voltage	V_{OH}	4.4	—	—	4.4	_	V	4.5	Vin = V_{IH} or V_{IL} \ I_{OH} = –20 μA
	_	4.18	_	—	4.13			4.5	I _{он} = –6 mА
	V_{OL}		_	0.1	_	0.1	V	4.5	Vin = V _{IH} or V _{IL} I_{OL} = 20 μ A
			—	0.26	—	0.33		4.5	$I_{OL} = 6 \text{ mA}$
Off-state output current	I _{oz}	—	—	±0.5	—	±5.0	μA	5.5	$ Vin = V_{IH} \text{ or } V_{IL}, \\ Vout = V_{CC} \text{ or } GND $
Input current	lin		_	±0.1	—	±1.0	μA	5.5	$Vin = V_{cc} \text{ or } GND$
Quiescent current	I _{cc}	_	_	4.0	_	40	μA	5.5	Vin = V_{cc} or GND, lout = 0 μ A

		Ta = 25°C		Ta = −40 to +85°C			Test Conditions		
Item	Symbol	Min	Тур	Мах	Min	Max	Unit	V_{cc} (V)	-
Maximum clock frequency	f_{max}	_	_	30	_	24	MHz	4.5	
Propagation delay	t _{PLH}	—	12	28	—	35	ns	4.5	
time	t _{PHL}	—	15	28	—	35	_	4.5	_
Output enable	t _{zL}	—	16	30	—	38	ns	4.5	
time	t _{zH}		15	30	—	38	_	4.5	_
Output disable	t _{LZ}	_	13	30	_	38	ns	4.5	
time	t _{HZ}	_	16	30	—	38	_	4.5	_
Setup time	t _{su}	20	2	_	25		ns	4.5	Data to clock
Hold time	t _h	5	0	_	6	_	ns	4.5	Clock to data
Pulse width	t _w	16	5	_	20	_	ns	4.5	Clock, output control
Output rise/fall time	t _{TLH} t _{THL}	—	4	12	_	15	ns	4.5	
Input capacitance	Cin	—	5	10		10	pF	_	

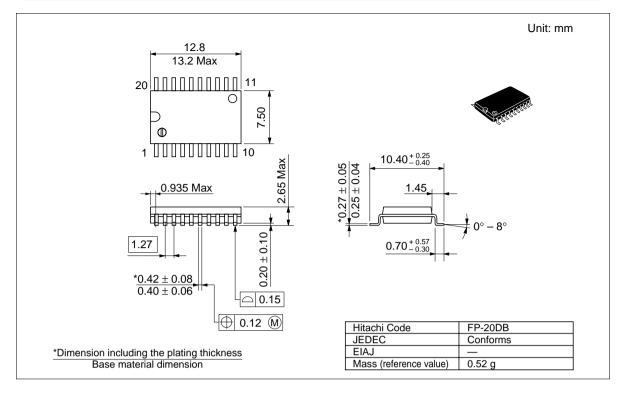
AC Characteristics ($C_L = 50 \text{ pF}$, Input $t_r = t_f = 6 \text{ ns}$)

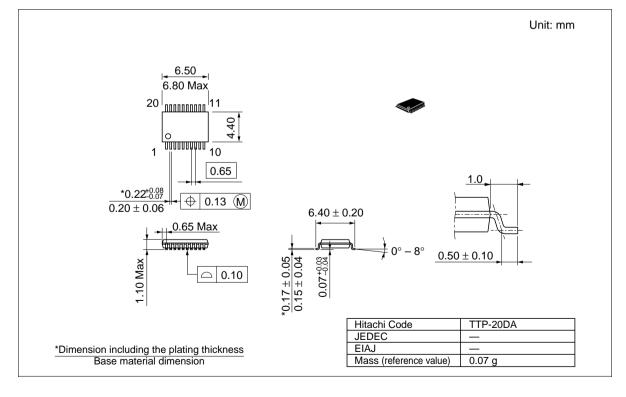
Package Dimensions











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